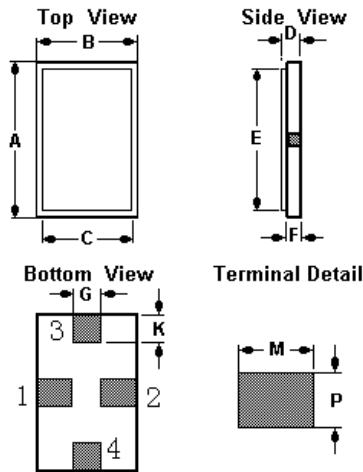


The NDR315S2 is a true one-port, surface-acoustic-wave (SAW) resonator in a low-profile SM-2 case. It provides reliable, fundamental-model, quartz frequency stabilization of fixed-frequency transmitters operating at **315 MHz**.

### 1.Package Dimension (SM-2)



Pin	Connection
1	Terminal1
2	Terminal2
3/4	Case Ground

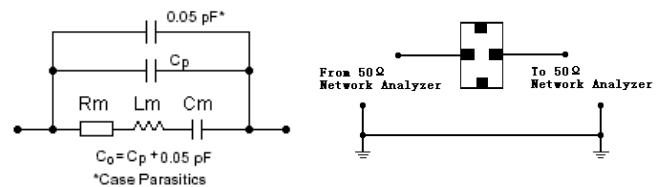
Sign	Data (unit: mm)	Sign	Data(unit:mm)
A	6.30	F	2.00
B	4.44	G	1.10
C	2.90	K	1.20
D	2.08	M	1.53
E	4.80	P	1.10

### 2.Marking

**NDR315S2**

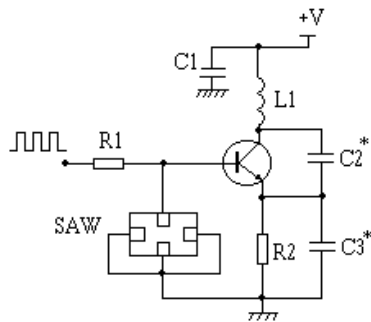
Color: Black or Blue

### 3.Equivalent LC Model and Test Circuit

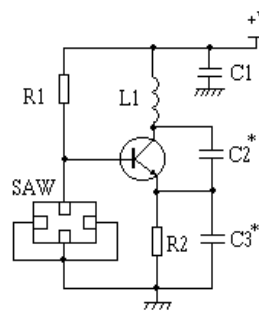


### 4.Typical Application Circuit

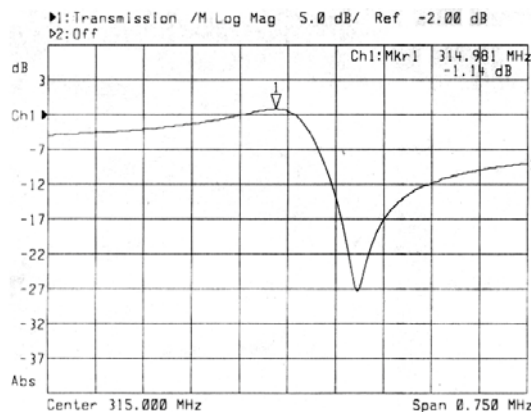
#### 1) Telecontrol Circuitry



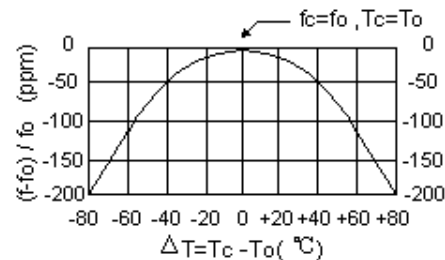
#### 2) Local Oscillator Application



### 5.Typical Frequency Response



### 6.Temperature Characteristics



The curve shown above accounts for resonator contribution only and does not include oscillator temperature characteristics.

## 7.Performance

### 7-1.Maximum Rating

Rating	Value	Units
CW RF Power Dissipation	+0	dBm
DC Voltage Between Any Two Pins	$\pm 30V$	VDC
Case Temperature	-40 to +85	$^{\circ}C$

### 7-2.Electronic Characteristics

Characteristic		Sym	Minimum	Typical	Maximum	Units
Center Frequency (+25 $^{\circ}C$ )	Absolute Frequency	$f_c$	314.925		315.075	MHz
	Tolerance from 315 MHz	$\Delta f_c$		$\pm 75$		kHz
Insertion Loss		IL		1.5	2.2	dB
Quality Factor	Unloaded Q	$Q_U$		12,500		
	50 $\Omega$ Loaded Q	$Q_L$		2,000		
Temperature Stability	Turnover Temperature	$T_O$	25	40	55	$^{\circ}C$
	Turnover Frequency	$f_O$		$f_c$		kHz
	Frequency Temperature Coefficient	FTC		0.037		ppm/ $^{\circ}C^2$
Frequency Aging Absolute Value during the First Year		$ f_A $		$\leq 10$		ppm/yr
DC Insulation Resistance Between Any Two Pins			1.0			M $\Omega$
RF Equivalent RLC Model	Motional Resistance	$R_M$		19	29	$\Omega$
	Motional Inductance	$L_M$		120.311		$\mu H$
	Motional Capacitance	$C_M$		2.1240		fF
	Pin 1 to Pin 2 Static Capacitance	$C_O$		2.5		pF

☺ **CAUTION: Electrostatic Sensitive Device. Observe precautions for handling !**

#### NOTES:

- Frequency aging is the change in  $f_c$  with time and is specified at +65 $^{\circ}C$  or less. Aging may exceed the specification for prolonged temperatures above +65 $^{\circ}C$ . Typically, aging is greatest the first year manufacture, decreasing in subsequent years.
- The center frequency,  $f_c$  is measured at the minimum insertion loss point,  $IL_{MIN}$  with the resonator in the 50  $\Omega$  test system (VSWR  $\leq 1.2:1$ ). The shunt inductance,  $L_{TEST}$ , is tuned for parallel resonance with  $C_O$  at  $f_c$ . Typically,  $f_{oscillator}$  or  $f_{transmitter}$  is less than the resonator  $f_c$ .
- Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
- Unless noted otherwise, case temperature  $T_c = +25^{\circ}C \pm 2^{\circ}C$ .
- The design, manufacturing process, and specifications of this device are subject to change without notice.
- Derived mathematically from one or more of the following directly measured parameters:  $f_c$ , IL, 3 dB bandwidth,  $f_c$  versus  $T_c$ , and  $C_O$ .
- Turnover temperature,  $T_O$ , is the temperature of maximum (or turnover) frequency,  $f_O$ . The nominal center frequency at any case temperature,  $T_C$ , may be calculated from:  $f = f_O [1 - FTC (T_O - T_C)^2]$ . Typically, oscillator  $T_O$  is 20 $^{\circ}C$  less than the specified resonator  $T_O$ .
- This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance  $C_O$  is the static (nonmotional) capacitance between the two terminals measured at low frequency (10MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05pF. Transducer parallel capacitance can be calculated as:  $C_P = C_O - 0.05pF$ .